NSN 5962-01-181-4286

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View Online at https://aerobasegroup.com/nsn/5962-01-181-4286

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Body Length:
0.960 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Static operation
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Case Outline Source And Designator:
D-6 mil-m-38510
Current Rating Per Characteristic:
5.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Solder
Product Name:
Mos static ram
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 7.0 volts power source
Memory Device Type:
Ram
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
18 printed circuit
Specification Data:
81349-mil-m-38510/238 government specification
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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